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Application Number	09/526,091			
Filing Date	March 15, 2000			
First Named Inventor	Michael L. Wach			
Group Art Unit	2874			
Examiner Name	Lee, J.			
Attorney Docket Number	06948.105009			

			F	OREIGN PAT	TENT DOCUMENTS			
	Cite	Foreign Patent Document			Date of Publication	0	Pages, Columns, Lines, Where	
	No. ¹	Office	³ Number Kind	Code ² (if known)	of Cited Document DD-MM-YYYY	Country	Relevant Passages or Relevant Figures Appear	T ⁶
ADL	AA	EP	0 611 097	A1	17/08/1994	EPO		
ML	AB	JP	10 327128	A1	08/12/1998	Japan		
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ADL	AE	wo	00/72416	A1	30/11/2000	PCT		
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Submitted f	for form 449/PTO		:	Application Number	09/526,091		
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Sheet	2	of	2	Attorney Docket Number	06948.105009		

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials *	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁶
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